

# INITIAL PRODUCT/PROCESS CHANGE NOTIFICATION Generic Copy

#### 13-FEB-2002

SUBJECT: ON Semiconductor Initial Product/Process Change Notification #12287

TITLE: Small Signal Schottky Process Consolidation in Zener Rectifier Wafer Fab

**EFFECTIVE DATE: 13-Jun-2002** 

AFFECTED CHANGE CATEGORY: ON Semiconductor Fab Site Subcontractor Fab Site Shrink Die

**AFFECTED PRODUCT DIVISION: Bipolar Discretes Products Div** 

**ADDITIONAL RELIABILITY DATA:** Available

Contact your local ON Semiconductor Sales Office or Laura Rivers <\$20636@onsemi.com>

**SAMPLES:** Contact your local ON Semiconductor Sales Office or Barbara Matteson <RM2230@onsemi.com>

#### FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact Sales Office or Donald Barlow <R39117@onsemi.com>

# **DISCLAIMER:**

Initial Product/Process Change Notification (IPCN) - First Notification distributed to customers. Distributed at least 120 days from the effective date of the change.

This is an 'early warning' about an upcoming change and contains general information regarding the change details and devices affected. It also contains at least a reliability qualification plan, but the actual qualification data will be identified in the Final Product/Process Change Notification (FPCN).

This notification will be followed by a Final Product/Process Change Notification (FPCN) at least 60 days from effective date of change.

#### **DESCRIPTION AND PURPOSE:**

ON Semiconductor wishes to notify its Customers that Small Signal Schottky Fabrication located in Primarion Wafer Fab, Tempe, Arizona and ON Semiconductor's Zener/Rectifier Wafer Fab, Phoenix, Arizona will be consolidated into ON Semiconductor's Zener/Rectifier Wafer Fab, Phoenix, Arizona. Some devices will undergo a non-active area die shrink in accordance with current design rules.

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**NOTE:** Only the following list of parts will be affected by the non active area die shrink.

MMDL101T1

MMBD352WT1

MBD110DWT1

MMBD101LT1

SMBD1015LT1

SMMBD101LT1

MMBD352LT1

SMBD1013LT3

MMBD353LT1

MMBD353LT3

MMBD354LT1

MMBD355LT1

MBD101

#### **QUALIFICATION PLAN:**

#### Reliability study including the following tests:

H3TRB

HTRB

Autoclave

**Electrical Distribution** 

TC

**ESD** 

DPA after H3TRB

IOL

Resistance to Solder Heat

DPA after TC

# AFFECTED DEVICE LIST (WITHOUT SPECIALS):

#### **PART**

BAS40-04LT1

BAS40-06LT1

BAS40LT1

BAS70-04LT1

BAS70LT1

BAT54ALT1

BAT54HT1

BAT54LT1

BAT54SLT1

BAT54SWT1

BAT54T1

BAT54WT1

LMCFD301WP

LMCFT54WP

MBD101

MBD110DWT1

**MBD301** 

MBD330DWT1

MBD54DWT1

**MBD701** 

MBD770DWT1

MMBD101LT1

MMBD301LT1

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MMBD301LT3

MMBD330T1

MMBD352LT1

MMBD352WT1

MMBD353LT1

MMBD353LT3

MMBD354LT1

MMBD355LT1

MMBD452LT1

MMBD701LT1

MMBD701LT3

MMBD717LT1

MMBD770T1

MMDL101T1

MMDL301T1

MMDL770T1

MMSD301T1

MMSD701T1

NSR15TW1T2

RB751V40T1

SBAS40-06LT1

SBAT54ALT1

SBAT54SLT1

SMMBD101LT1

SMMBD301LT1

SMMBD301LT3

SMMBD701LT1

SMMBD701LT3

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